

Undervoltage Sensing Circuit

The MC34064 is an undervoltage sensing circuit specifically designed for use as a reset controller in microprocessor-based systems. It offers the designer an economical solution for low voltage detection with a single external resistor. The MC34064 features a trimmed-in-package bandgap reference, and a comparator with precise thresholds and built-in hysteresis to prevent erratic reset operation. The open collector reset output is capable of sinking in excess of 10 mA, and operation is guaranteed down to 1.0 V input with low standby current. These devices are packaged in 3-pin TO-226AA, 8-pin SO–8 and MICRO–8 surface mount packages.

Applications include direct monitoring of the 5.0 V MPU/logic power supply used in appliance, automotive, consumer and industrial equipment.

- Trimmed-In-Package Temperature Compensated Reference
- Comparator Threshold of 4.6 V at 25°C
- Precise Comparator Thresholds Guaranteed Over Temperature
- Comparator Hysteresis Prevents Erratic Reset
- Reset Output Capable of Sinking in Excess of 10 mA
- Internal Clamp Diode for Discharging Delay Capacitor
- Guaranteed Reset Operation with 1.0 V Input
- Low Standby Current
- Economical TO-226AA, SO-8 and MICRO-8 Surface Mount Packages

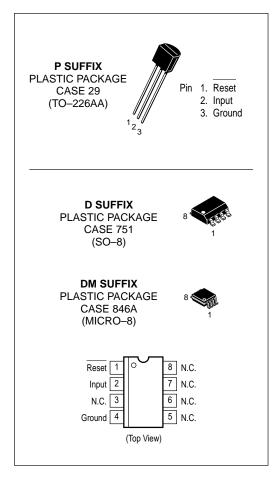
Representative Block Diagram Input 2 (2) Reset 1 (1) 1.2 V_{ref} Sink Only Positive True Logic Pin numbers adjacent to terminals are for the 3-pin TO-226AA package. Pin numbers in parenthesis are for the 8-lead packages.

This device contains 21 active transistors.

MC34064 MC33064

UNDERVOLTAGE SENSING CIRCUIT

SEMICONDUCTOR TECHNICAL DATA



ORDERING INFORMATION

Device	Operating Temperature Range	Package
MC34064D-5		SO-8
MC34064DM-5	$T_A = 0^\circ \text{ to } +70^\circ \text{C}$	MICRO-8
MC34064P-5		TO-226AA
MC33064D-5		SO-8
MC33064DM-5	$T_A = -40^{\circ} \text{ to } +85^{\circ}\text{C}$	MICRO-8
MC33064P-5		TO-226AA

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Power Input Supply Voltage	V _{in}	-1.0 to 10	V
Reset Output Voltage	٧o	10	V
Reset Output Sink Current (Note 1)	^I Sink	Internally Limited	mA
Clamp Diode Forward Current, Pin 1 to 2 (Note 1)	ΙF	100	mA
Power Dissipation and Thermal Characteristics P Suffix, Plastic Package			
Maximum Power Dissipation @ T _A = 25°C Thermal Resistance, Junction–to–Air	P _D R ₀ JA	625 200	mW °C/W
D Suffix, Plastic Package Maximum Power Dissipation @ T _A = 25°C Thermal Resistance, Junction–to–Air DM Suffix, Plastic Package	P _D R _θ JA	625 200	mW °C/W
Maximum Power Dissipation @ T _A = 25°C Thermal Resistance, Junction–to–Air	P _D R _θ JA	520 240	mW °C/W
Operating Junction Temperature	TJ	+150	°C
Operating Ambient Temperature MC34064 MC33064	ТА	0 to +70 -40 to +85	°C
Storage Temperature Range	T _{stg}	-65 to +150	°C

NOTE: ESD data available upon request.

 $\textbf{ELECTRICAL CHARACTERISTICS} \ (\text{For typical values T}_{A} = 25^{\circ}\text{C}, \text{ for min/max values T}_{A} \text{ is the operating ambient temperature range} \\$ that applies [Notes 2 and 3] unless otherwise noted.)

Characteristics	Symbol	Min	Тур	Max	Unit
COMPARATOR		•		•	•
Threshold Voltage High State Output (V _{in} Increasing) Low State Output (V _{in} Decreasing) Hysteresis	VIH VIL VH	4.5 4.5 0.01	4.61 4.59 0.02	4.7 4.7 0.05	V
RESET OUTPUT	<u>.</u>				
Output Sink Saturation $ \begin{aligned} &(\text{V}_{\text{in}} = 4.0 \text{ V}, \text{I}_{\text{Sink}} = 8.0 \text{ mA}) \\ &(\text{V}_{\text{in}} = 4.0 \text{ V}, \text{I}_{\text{Sink}} = 2.0 \text{ mA}) \\ &(\text{V}_{\text{in}} = 1.0 \text{ V}, \text{I}_{\text{Sink}} = 0.1 \text{ mA}) \end{aligned} $	VoL	- - -	0.46 0.15 –	1.0 0.4 0.1	V
Output Sink Current (V _{in} , Reset = 4.0 V)	lSink	10	27	60	mA
Output Off-State Leakage (Vin, Reset = 5.0 V)	ЮН	-	0.02	0.5	μΑ
Clamp Diode Forward Voltage, Pin 1 to 2 (IF = 10 mA)	VF	0.6	0.9	1.2	٧
TOTAL DEVICE		•		•	•
Operating Input Voltage Range	V _{in}	1.0 to 6.5	-	_	٧
Quiescent Input Current (Vin = 5.0 V)	l _{in}	_	390	500	μΑ

Figure 1. Reset Output Voltage versus Input Voltage

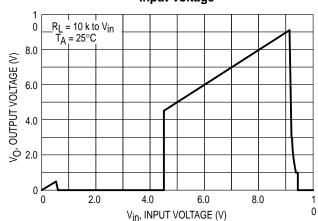


Figure 2. Reset Output Voltage versus Input Voltage

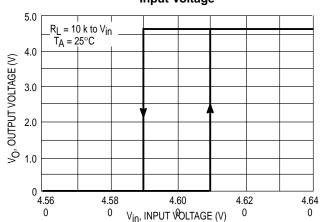


Figure 3. Comparator Threshold Voltage versus Temperature

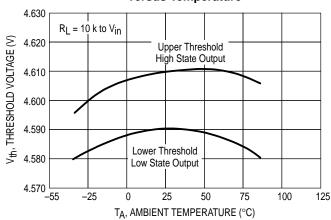


Figure 4. Input Current versus Input Voltage

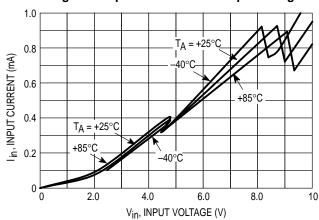


Figure 5. Reset Output Saturation versus Sink Current

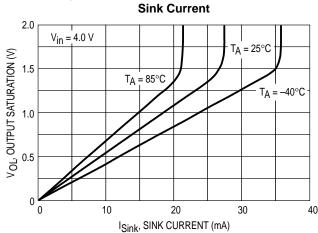


Figure 6. Reset Delay Time

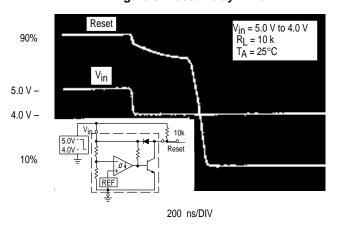


Figure 7. Clamp Diode Forward Current versus Voltage

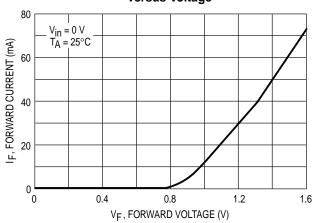


Figure 8. Low Voltage Microprocessor Reset

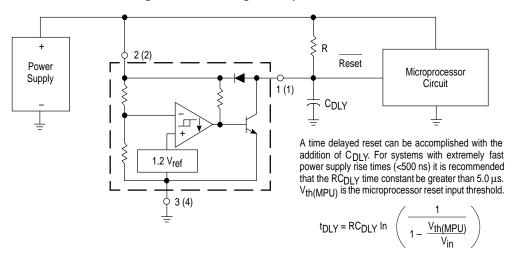
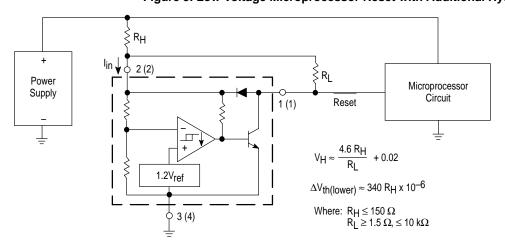


Figure 9. Low Voltage Microprocessor Reset with Additional Hysteresis



Comparator hysteresis can be increased with the addition of resistor R_H . The hysteresis equation has been simplified and does not account for the change of input current l_{in} as V_{CC} crosses the comparator threshold (Figure 4). An increase of the lower threshold $\Delta V_{th(lower)}$ will be observed due to l_{in} which is typically 340 μA at 4.59 V. The equations are accurate to $\pm 10\%$ with R_H less than 150 Ω and R_L between 1.5 $k\Omega$ and 10 $k\Omega$.

Test Data					
VH (mV)	$^{\Delta V_{ ext{th}}}_{ ext{(mV)}}$	R _H (Ω)	RL (kΩ)		
20	0	0	0		
51	3.4	10	1.5		
40	6.8	20	4.7		
81	6.8	20	1.5		
71	10	30	2.7		
112	10	30	1.5		
100	16	47	2.7		
164	16	47	1.5		
190	34	100	2.7		
327	34	100	1.5		
276	51	150	2.7		
480	51	150	1.5		

Figure 10. Voltage Monitor

Figure 11. Solar Powered Battery Charger

Solar Cells

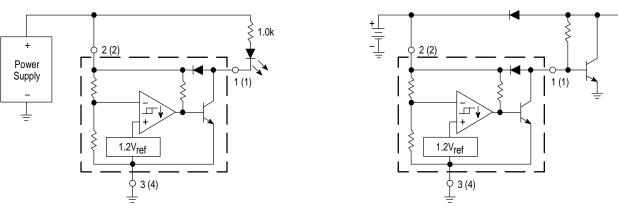


Figure 12. Low Power Switching Regulator

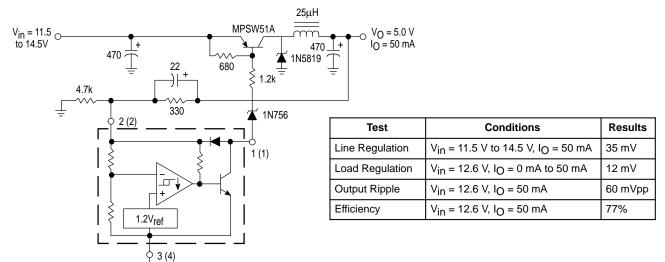
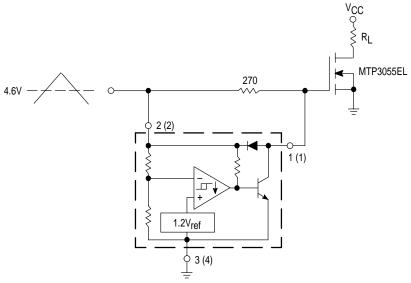


Figure 13. MOSFET Low Voltage Gate Drive Protection



Overheating of the logic level power MOSFET due to insufficient gate voltage can be prevented with the above circuit. When the input signal is below the 4.6 V threshold of the MC34064, its output grounds the gate of the ℓ MOSFET.

OUTLINE DIMENSIONS

SEATING PLANE

P SUFFIX PLASTIC PACKAGE CASE 29-04 (TO-226AA) ISSUE AD

SECTION X-X

- NOTES:

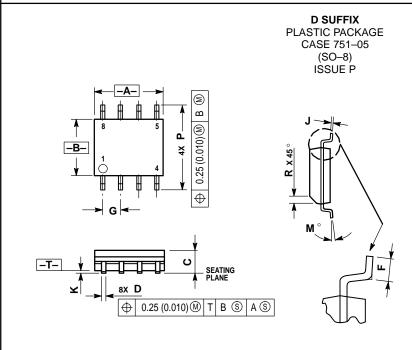
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

 2. CONTROLLING DIMENSION: INCH.

 3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.

 4. DIMENSION F APPLIES BETWEEN P AND L. DIMENSION D AND J APPLY BETWEEN L AND K MINIMUM. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION HIS MINIMUM. IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.175	0.205	4.45	5.20
В	0.170	0.210	4.32	5.33
С	0.125	0.165	3.18	4.19
D	0.016	0.022	0.41	0.55
F	0.016	0.019	0.41	0.48
G	0.045	0.055	1.15	1.39
Н	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500		12.70	
L	0.250		6.35	
N	0.080	0.105	2.04	2.66
Р		0.100		2.54
R	0.115		2.93	
V	0.135		3.43	



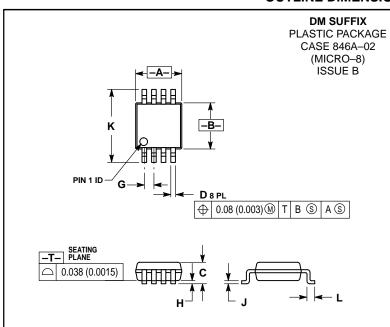
- VOIES.

 1. DIMENSIONS A AND B ARE DATUMS AND T IS A DATUM SURFACE.

 2. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 3. DIMENSIONS ARE IN MILLIMETER.
 4. DIMENSION A AND B DO NOT INCLUDE MOLD
- PROTRUSION.
 MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.
- DIMENSION D DOES NOT INCLUDE MOLD PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIMETERS			
DIM	MIN	MAX		
Α	4.80	5.00		
В	3.80	4.00		
С	1.35	1.75		
D	0.35	0.49		
F	0.40	1.25		
G	1.27	1.27 BSC		
J	0.18	0.25		
K	0.10	0.25		
M	0°	7 °		
P	5.80	6.20		
R	0.25	0.50		

OUTLINE DIMENSIONS



- NOTES:

 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

 2. CONTROLLING DIMENSION: MILLIMETER.

 3. DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH, PROTRUSIONS OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.

 4. DIMENSION D DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION. HALL NOT EXCEED 0.25 (0.010) PER SIDE. PER SIDE.

	MILLIMETERS		INC	HES
DIM	MIN	MAX	MIN	MAX
Α	2.90	3.10	0.114	0.122
В	2.90	3.10	0.114	0.122
С		1.10		0.043
D	0.25	0.40	0.010	0.016
G	0.65	0.65 BSC		BSC
Н	0.05	0.15	0.002	0.006
J	0.13	0.23	0.005	0.009
K	4.75	5.05	0.187	0.199
L	0.40	0.70	0.016	0.028

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